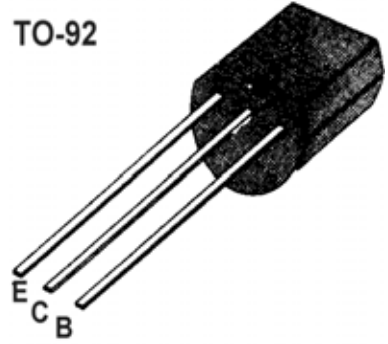


■■ APPLICATION: General Purpose Amplifier Applications..

■■ MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$)

PARAMETER	SYMBOL	RATING	UNIT
Collector-base voltage	V_{CBO}	-55	V
Collector-emitter voltage	V_{CEO}	-55	V
Emitter-base voltage	V_{EBO}	-5	V
Collector current	I_C	-100	mA
Collector Power Dissipation	P_C	300	mW
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	- 55~150	$^{\circ}\text{C}$

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■■ ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
DC Current Gain	h_{FE}	160		500		$V_{CE} = -12\text{V}$, $I_C = -2\text{mA}$
Collector Cut-off Current	I_{CBO}			-0.1	μA	$V_{CB} = -18\text{V}$, $I_E = 0$
Emitter Cut-off Current	I_{EBO}			-0.05	μA	$V_{EB} = -2\text{V}$, $I_C = 0$
Collector-Base Breakdown Voltage	BV_{CBO}	-55			V	$I_C = -0.1\text{mA}$, $I_E = 0$
Collector-Emitter Breakdown Voltage	BV_{CEO}	-55			V	$I_C = -1\text{mA}$, $I_B = 0$
Emitter-Base Breakdown Voltage	BV_{EBO}	-5			V	$I_E = -0.1\text{mA}$, $I_C = 0$
Base-Emitter Voltage	V_{BE}		-0.66	-0.75	V	$V_{CE} = -12\text{V}$, $I_C = -2\text{mA}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		-0.1	-0.5	V	$I_C = -10\text{mA}$, $I_B = -1\text{mA}$
Gain bandwidth product	f_T		200		MHz	$I_C = -2\text{mA}$, $V_{CE} = -12\text{V}$
Common Base Output Capacitance	C_{ob}		2		PF	$V_{CB} = -10\text{V}$, $I_E = 0$, $f = 1\text{MHz}$

■■ h_{FE} Classification

Classification	C	D
h_{FE}	160~320	250~500